

Power transistor (60V, 2A)

2SC5880

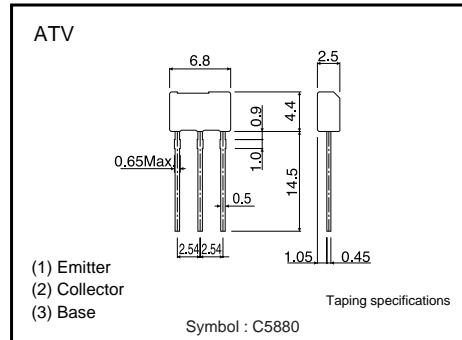
●Features

- 1) High speed switching.
(t_f : Typ. : 35ns at $I_c = 2A$)
- 2) Low saturation voltage, typically
(Typ. : 200mV at $I_c = 1.0A, I_B = 100mA$)
- 3) Strong discharge power for inductive load and capacitance load.
- 4) Complements the 2SA2093

●Applications

Low frequency amplifier
High speed switching

●Dimensions (Unit : mm)



●Structure

NPN Silicon epitaxial planar transistor

●Packaging specifications

Type	Package	Taping
	Code	TV2
	Basic ordering unit (pieces)	2500
2SC5880		○

●Absolute maximum ratings ($T_a=25^\circ\text{C}$)

Parameter	Symbol	Limits	Unit	
Collector-base voltage	V_{CB0}	60	V	
Collector-emitter voltage	V_{CE0}	60	V	
Emitter-base voltage	V_{EB0}	6	V	
Collector current	DC	I_c	2	A
	Pulsed	I_{cP}	4	A *
Power dissipation	P_c	1.0	W	
Junction temperature	t_j	150	$^\circ\text{C}$	
Range of storage temperature	t_{stg}	-55 to 150	$^\circ\text{C}$	

* $P_w=10\text{ms}$

Transistors

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Collector-emitter breakdown voltage	BV_{CEO}	60	–	–	V	$I_C=1\text{mA}$
Collector-base breakdown voltage	BV_{CBO}	60	–	–	V	$I_C=100\mu\text{A}$
Emitter-base breakdown voltage	BV_{EBO}	6	–	–	V	$I_E=100\mu\text{A}$
Collector cut-off current	I_{CBO}	–	–	1.0	μA	$V_{CB}=40\text{V}$
Emitter cut-off current	I_{EBO}	–	–	1.0	μA	$V_{EB}=4\text{V}$
Collector-emitter saturation voltage	$V_{CE(sat)}$	–	200	500	mV	$I_C=1.0\text{A}$ $I_B=0.1\text{A}$
DC current gain	h_{FE}	120	–	390	–	$V_{CE}=2\text{V}$ $I_C=100\text{mA}$
Transition frequency	f_r	–	200	–	MHz	$V_{CE}=10\text{V}$ $I_E=-100\text{mA}$ $f=10\text{MHz}$
Corrector output capacitance	C_{ob}	–	10	–	pF	$V_{CB}=10\text{V}$ $I_E=0\text{mA}$ $f=1\text{MHz}$
Turn-on time	t_{on}	–	50	–	ns	$I_C=2\text{A}$ $I_{B1}=200\text{mA}$ $I_{B2}=-200\text{mA}$
Storage time	t_{stg}	–	120	–	ns	$V_{CC}\approx 25\text{V}$
Fall time	t_f	–	35	–	ns	

*Non repetitive pulse

● h_{FE} RANK

Q	R
120–270	180–390

●Electrical characteristic curves

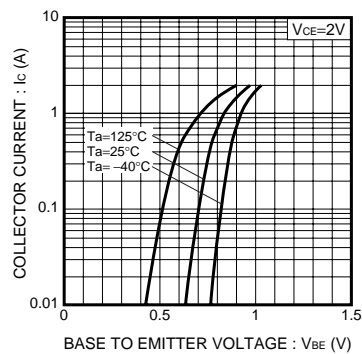


Fig.1 Grounded Emitter Propagation Characteristics

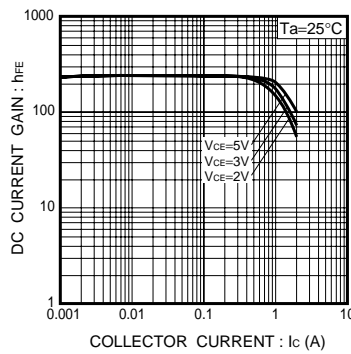


Fig.2 DC Current Gain vs. Collector Current (I)

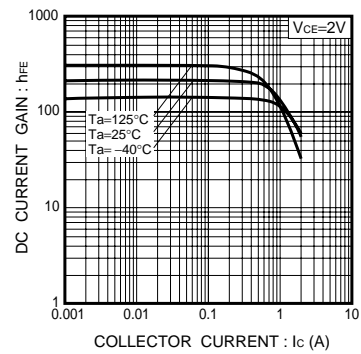


Fig.3 DC Current Gain vs. Collector Current (II)

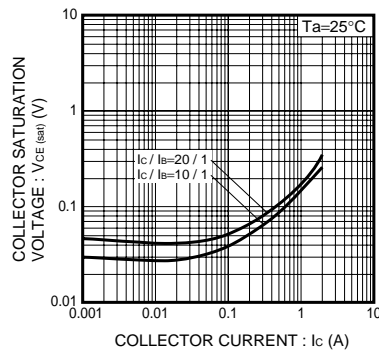


Fig.4 Collector-Emitter Saturation Voltage vs. Collector Current (I)

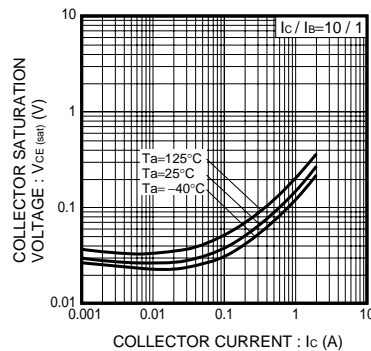


Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current (II)

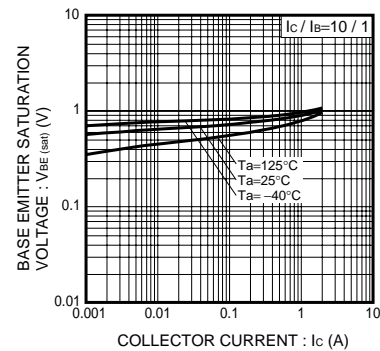


Fig.6 Base-Emitter Saturation Voltage vs. Collector Current

Transistors

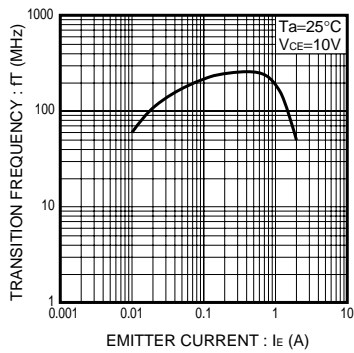


Fig.7 Transition Frequency

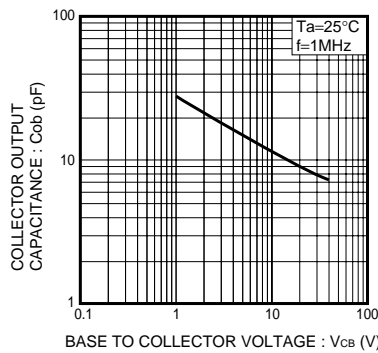


Fig.8 Collector Output Capacitance

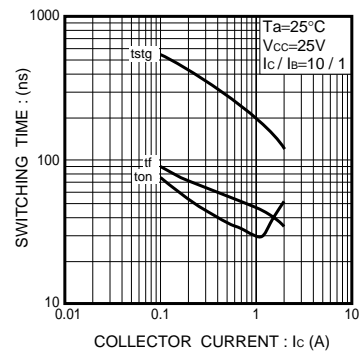


Fig.9 Switching Time

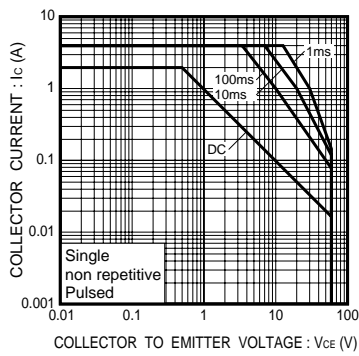
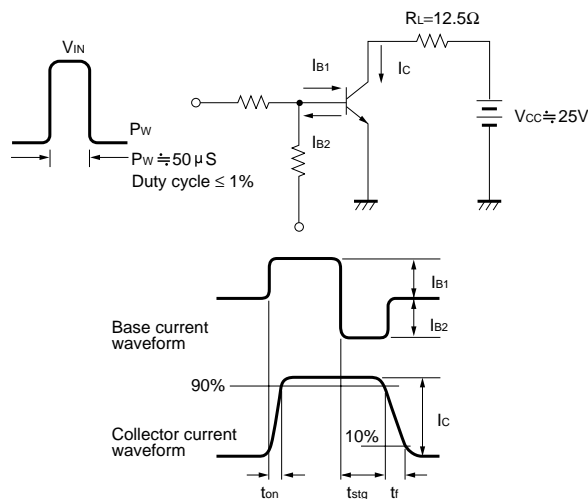


Fig.10 Safe Operating Area

●Switching characteristics measurement circuits



Notes

- No technical content pages of this document may be reproduced in any form or transmitted by any means without prior permission of ROHM CO.,LTD.
- The contents described herein are subject to change without notice. The specifications for the product described in this document are for reference only. Upon actual use, therefore, please request that specifications to be separately delivered.
- Application circuit diagrams and circuit constants contained herein are shown as examples of standard use and operation. Please pay careful attention to the peripheral conditions when designing circuits and deciding upon circuit constants in the set.
- Any data, including, but not limited to application circuit diagrams information, described herein are intended only as illustrations of such devices and not as the specifications for such devices. ROHM CO.,LTD. disclaims any warranty that any use of such devices shall be free from infringement of any third party's intellectual property rights or other proprietary rights, and further, assumes no liability of whatsoever nature in the event of any such infringement, or arising from or connected with or related to the use of such devices.
- Upon the sale of any such devices, other than for buyer's right to use such devices itself, resell or otherwise dispose of the same, no express or implied right or license to practice or commercially exploit any intellectual property rights or other proprietary rights owned or controlled by
- ROHM CO., LTD. is granted to any such buyer.
- Products listed in this document are no antiradiation design.

The products listed in this document are designed to be used with ordinary electronic equipment or devices (such as audio visual equipment, office-automation equipment, communications devices, electrical appliances and electronic toys).

Should you intend to use these products with equipment or devices which require an extremely high level of reliability and the malfunction of which would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), please be sure to consult with our sales representative in advance.

It is our top priority to supply products with the utmost quality and reliability. However, there is always a chance of failure due to unexpected factors. Therefore, please take into account the derating characteristics and allow for sufficient safety features, such as extra margin, anti-flammability, and fail-safe measures when designing in order to prevent possible accidents that may result in bodily harm or fire caused by component failure. ROHM cannot be held responsible for any damages arising from the use of the products under conditions out of the range of the specifications or due to non-compliance with the NOTES specified in this catalog.

Thank you for your accessing to ROHM product informations.

More detail product informations and catalogs are available, please contact your nearest sales office.

ROHM Customer Support System

THE AMERICAS / EUROPE / ASIA / JAPAN

www.rohm.com

Contact us : webmaster@rohm.co.jp